http://www.smc-diodes.com - sales@ smc-diodes.com •

ST5100BAX

ST5100BAX SCHOTTKY RECTIFIER

Features

- 150 °C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm V _{rwm} Vr	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc =100°C, rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T_c =25°C	120	A

Electrical Characteristics:

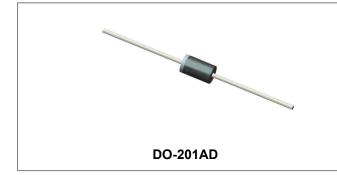
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 2.5A, Pulse, T _J = 25 °C	0.55	-	V
		@ 5A, Pulse, T _J = 25 °C	0.70	0.75	v
	VF2	@ 2.5A, Pulse, T _J = 125 °C	0.49	-	V
		@ 5A, Pulse, T _J = 125 °C	0.60	0.70	v
Reverse Current*	I _{R1}	$@V_R$ = Rated V _R , Pulse, T _J = 25 °C	0.006	0.12	mA
	I _{R2}	$@V_R$ = Rated V _R , Pulse, T _J = 125 °C	2	18	mA
Junction Capacitance C _T		@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	220	-	pF

* Pulse width < 300 μ s, duty cycle < 2%

Cathode Anode



Data Sheet N1633, Rev.A



RoHS 🗭





ST5100BAX

Technical Data Data Sheet N1633, Rev.A RoHS 🗭

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	5	°C/W
Approximate Weight	wt	-	1.02	g

Ratings and Characteristics Curves

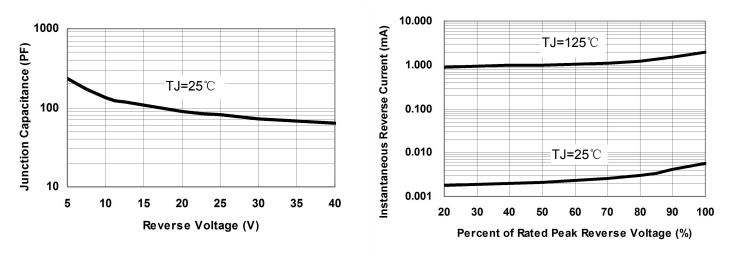


Fig.1-Typical Junction Capacitance



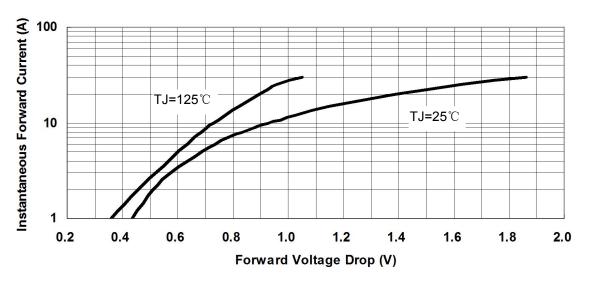


Fig.3-Typical Forward Voltage Drop Characteristics

• http://www.smc-diodes.com - sales@ smc-diodes.com •



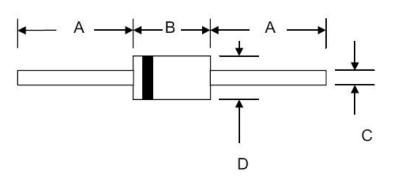
ST5100BAX

Pb

RoHS

Technical Data Data Sheet N1633, Rev.A

Mechanical Dimensions DO-201AD



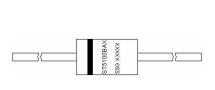
	Millim	neters	Inches	
SYMBOL	Min.	Max.	Min.	Max.
А	25.4	-	1.000	-
В	8.50	9.50	0.335	0.374
С	1.2	1.3	0.048	0.052
D	5.0	5.6	0.197	0.220

Ordering Information

Device	Package	Shipping
ST5100BAX	DO-201AD (Pb-Free)	1250pcs / tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

- ST = Device Type
- = Forward Current (5A) = Reverse Voltage (100V) 100
 - = Package type
- BAX SSG = SSG
 - = Year

5

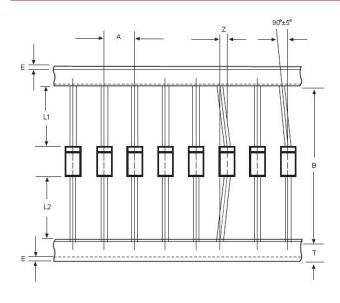
YY

Т

- WW = Week
 - = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DO-201AD



SYMBOL	Millimeters		
	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	



Technical Data Data Sheet N1633, Rev.A





DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC - Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC - Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC - Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC - Sangdest Microelectronics (Nanjing) Co., Ltd.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..

http://www.smc-diodes.com - sales@ smc-diodes.com -